Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:		
Metal		
Overall Length:		
0.212 inches		
Overall Diameter:		
0.120 inches		
Function For Which Designed:		
Varactor diode		
Mounting Method:		
Press fit		
Semiconductor Material:		
Silicon		
Voltage Rating In Volts Per Cha	aracteristic:	
30.0 reverse voltage, instantane	OUS	
Power Rating Per Characteristi	c:	
300.0 milliwatts small-signal inpu	t power, common-collector preset	
Capacitance Rating In Picofara	ds:	
Between 0.19 and 0.25		
Maximum Operating Tempurate	ure Per Measurement Point:	
175.0 degrees celsius ambient ai	r	
Terminal Type And Quantity:		
2 ferrule		
Shelf Life:		
N/a		
Unit Of Measure:		
Demilitarization:		
No		
Fiig:		
A110a0		